

## GaAs SPST High Isolation Terminated Switch 0.5 - 2.0 GHz



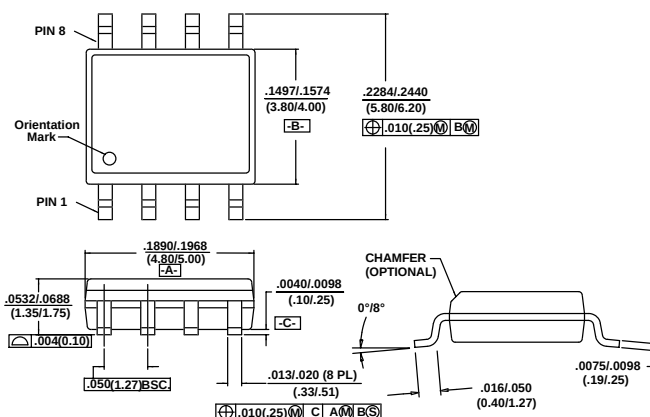
## Features

- Terminated RF Output
- High Isolation: 42 dB upto 2 GHz
- Single Positive Control
- CMOS Compatible Logic
- Low Cost SOIC-8 Plastic Package

### Description

M/A-COM's SW-393 is a GaAs Monolithic SPST terminated switch in a low cost SOIC 8-lead plastic package. The SW-393 is ideally suited for use where low power consumption and high isolation are required. Typical applications include PCS and GSM LO switching, switch matrices and switched filter banks in systems such as radio and cellular equipment.

The SW-393 is fabricated using a mature 1-micron gate length GaAs MESFET process. The process features full chip passivation for increased performance and reliability.

SOIC-8<sup>1</sup>

1. Dimensions are in: inches/mm

## Ordering Information

| Part Number | Package                            |
|-------------|------------------------------------|
| SW-393 PIN  | SOIC 8-Lead Plastic Package        |
| SW-393TR    | Forward Tape and Reel <sup>1</sup> |

1. Refer to Application Note M513 for reel size information.

**Electrical Specifications:  $T_A = +25^{\circ}\text{C}^1$**

| Parameter                             | Test Conditions                          | Units   | Min. | Typ.  | Max. |
|---------------------------------------|------------------------------------------|---------|------|-------|------|
| Insertion Loss                        | 0.5 - 2.0 GHz                            | dB      |      | 1.6   | 1.8  |
| Isolation                             | 0.5 - 1.0 GHz                            | dB      | 50   | 53    |      |
|                                       | 1.0 - 2.0 GHz                            | dB      | 40   | 42    |      |
| VSWR                                  | 0.5 - 1.5 GHz                            |         |      | 1.5:1 |      |
|                                       | 0.5 - 2.0 GHz                            |         |      | 1.7:1 |      |
| 1 dB Compression                      | Input Power, +5V Control/Supply          | 0.5 GHz |      | 25    |      |
|                                       |                                          | 0.9 GHz |      | 25    |      |
|                                       |                                          | 1.5 GHz |      | 26    |      |
| T <sub>rise</sub> , T <sub>fall</sub> | 10% to 90% RF, 90% to 10% RF             | μS      |      | 9     |      |
| T <sub>on</sub> , T <sub>off</sub>    | 50% Control to 90% RF, Control to 10% RF | μS      |      | 9     |      |
| Transients                            | In-band                                  | mV      |      | 50    |      |
| Input IP <sub>2</sub>                 | 2-Tone, 5 MHz spacing,                   | 0.5 GHz |      | 53    |      |
|                                       | +10 dBm each                             | 0.9 GHz |      | 58    |      |
| Input IP <sub>3</sub>                 | 2-Tone, 5 MHz spacing,                   | 0.5 GHz |      | 39    |      |
|                                       | +10 dBm each                             | 0.9 GHz |      | 38    |      |

1. All measurements taken at 900 MHz in a 50Ω system unless otherwise specified. Loss varies at 0.003 dB/°C.

Absolute Maximum Ratings<sup>1</sup>

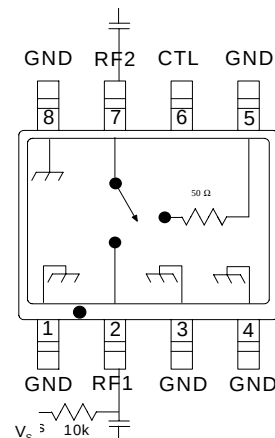
| Parameter                               | Absolute Maximum |
|-----------------------------------------|------------------|
| Input Power                             | +34 dBm          |
| Operating Voltage ( $V_S$ , $V_{CTL}$ ) | +8.5 Volts       |
| Operating Temperature                   | -40°C to +85°C   |
| Storage Temperature                     | -65°C to +150°C  |

1. Exceeding any one or a combination of these limits may cause permanent damage.

## Truth Table

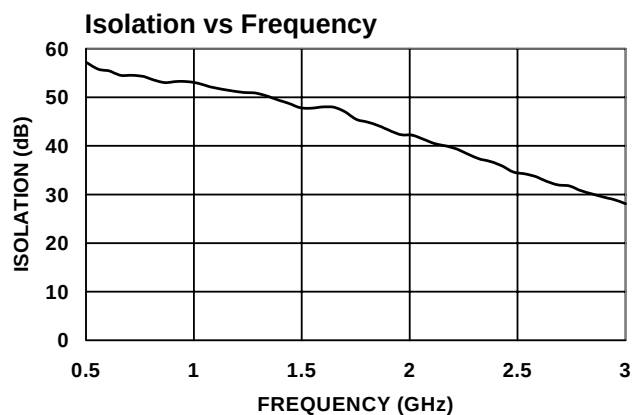
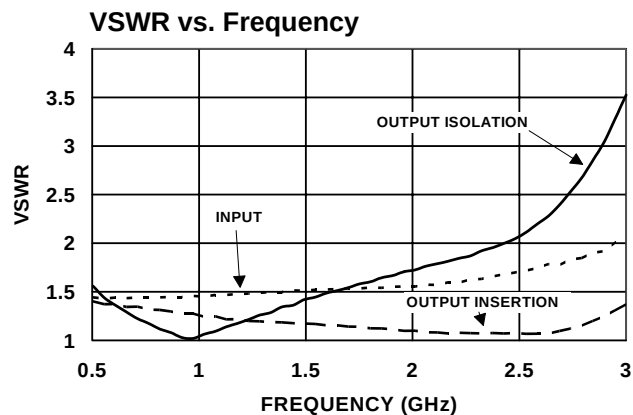
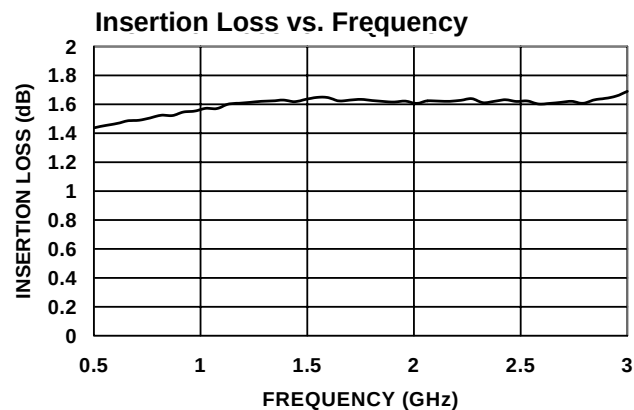
| Control | RF1 - RF2 |
|---------|-----------|
| 0       | Off       |
| 1       | On        |

"0" =  $0 \pm 0.2$  Vdc  
 "1" =  $+5 \pm 0.2$  Vdc  
 $V_S$  =  $+5 \pm 0.2$  Vdc

Functional Schematic<sup>1</sup>

1. Blocking capacitors are required on all RF ports.  $V_S$  can be applied at RF1 or RF2 using 10K or greater pull-up resistor.

## Typical Performance Curves



V2.00